Análise de Resultados de Experimentos

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1 Semi-analytical analysis

Let's begin the pre-analysis for solving the problem of a beam splitter by studiying some of the materials used in waveguides in the integrated circuit context. The dispersion relation for Ag_3AsS_3 , TiO_2 , Si_3N_4 , and SiO_2 are equated in Eq. 1a, 1b, 1c, 1d, respectively, and are shown in Fig. 1a. Ag_3AsS_3 is used in nonlinear optics: second-harmonic generation, TiO_2 is used in high-confinement waveguides in the visible and near-infrared spectrum, Si_3N_4 is used in nonlinear optics for supercontinuum generation, and SiO_2 is used in optical fibers and planar waveguides.

$$n_{Ag_3AsS_3} = \sqrt{7.483 + \frac{0.474}{\lambda^2 - 0.09} - 0.0019\lambda^2}$$
 (1a)

$$n_{TiO_2} = \sqrt{5.913 + \frac{0.2441}{\lambda^2 - 0.0803}} \tag{1b}$$

$$n_{Si_3N_4} = \sqrt{1 + \frac{2.8939\lambda^2}{\lambda^2 - 0.13967^2}} \tag{1c}$$

$$n_{SiO_2} = \sqrt{1 + \frac{0.6961663\lambda^2}{\lambda^2 - 0.0684043^2} + \frac{0.4079426\lambda^2}{\lambda^2 - 0.1162414^2} + \frac{0.8974794\lambda^2}{\lambda^2 - 9.896161}}$$
 (1d)

Figure 1b shows the critical angle as a function of the cladding refractive index for the core made of the materials stated above. You can see that as we increase the cladding RI (refractive index), the modes become more leaky and the critical angle increases, being easier to couple light in the waveguide. In the opposite direction, as we increase the core RI, the modes become more confined and the critical angle decreases, being harder to couple light in the waveguide.

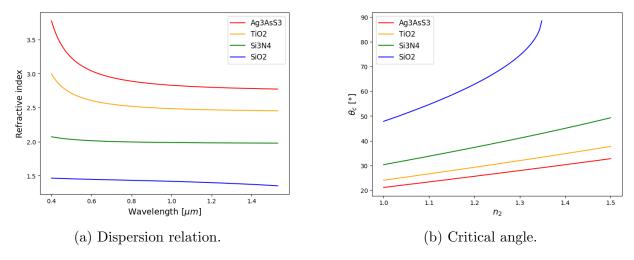


Figure 1: Study of different materials for the core of the waveguide.

1.1 Planar dielectric waveguide

A important parameter for waveguides is the numerical aperture (NA), which is a measure of the light acceptance angle in the waveguide. It is given by Eq. 2, where n_1 is the refractive index of the core and n_2 is the refractive index of the cladding.

$$NA = \sqrt{n_1^2 - n_2^2} \tag{2}$$

The other important parameter is the critical angle (θ_c) , given by Eq. 3, related to the maximum angle of incidence for total internal reflection to occur.

$$\theta_c = \sin^{-1}\left(\frac{n_2}{n_1}\right) \tag{3}$$

The results for these parameters for SiO_2 and TiO_2 are shown in Tab. ??.

Material	$\theta_c[^{\circ}]$	NA
SiO_2	47.8	0.906
TiO_2	24.1	2.240

Table 1: Numerical aperture and critical angle for different core materials, considering air as the cladding.

A approximation for the number of TE modes is given by (4), where d is the core thickness, λ is the wavelength, and NA is the numerical aperture.

$$M_{the} \doteq 2\frac{d}{\lambda}NA\tag{4}$$

The exact number of modes can be found by solving the characteristic equation for the planar dielectric waveguide, given by Eq. 5, where m=0,1,2,... is the mode order, $k_0=2\pi/\lambda$ is the free space wavenumber, θ_m is the angle of incidence for the m-th mode, and θ_c is the critical angle.

$$f_1(\sin(\theta_m)) \equiv \tan\left[\pi\left(\frac{\sin(\theta_m)d}{\lambda} - \frac{m}{2}\right)\right] = \sqrt{\frac{\sin^2(\overline{\theta}_c)}{\sin(\theta_m)^2} - 1} \equiv f_2(\sin(\theta_m))$$
 (5)

The plot for f_1 and f_2 to help visualize the possible modes for the waveguide is shown in Fig. 2a. Using the bisection or the Newton-Raphson methods based on the guess interval or point aided by Fig. 2a, we can find the intersections of f_1 and f_2 to further calculate the propagation constant β_m and the effective RI (ERI) $n_{eff,m}$ for the m-th order mode. The resultant modes are shown in Fig. 2b where the black dots are the modes, the green curve have radius n_2k_0 and the blue curve have radius n_2k_0 . For a planal dielectric waveguide with SiO_2 as the core and with thickness $d = 10\mu$ we got 5 possible TE modes.

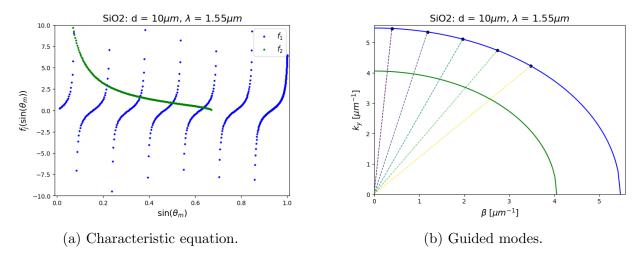


Figure 2: Solution for the guided modes in a planar dielectric waveguide with a SiO_2 core, $d = 10\mu m$ and $\lambda = 1.55\mu m$.

A comparison between the approximation and exact number of TE modes is put in Tab. ?? as we increase the thickness of the core, by consequence, we increase the number of possible modes. So, when it is possible to manually count the number of modes, use this technique to obtain the exact value, since the approximate value can diverge much.

$d[\mu m]$	M_{app}	M_{exa}
1	2	1
5	6	3
10	12	5

Table 2: Approximate and exact number of TE modes for different core thicknesses for the SiO_2 waveguide.

Using the condition $k_0n_2 \leq \beta_m \leq k_0n_1$ to keep only the guided modes, we get the values for the propagation constant and the corresponding ERI for SiO_2 -core waveguide in Tab. 3a. Running the same simulation but for the TiO_2 -core waveguide, we get the values of Tab. 3b.

Mode	$\beta[\mu m^{-1}]$	n_{eff}
0	5.419	1.337
1	5.008	1.235
2	4.171	1.029
	(a) SiO_2 .	

Mode	$\beta[\mu m^{-1}]$	n_{eff}
0	9.847	2.429
1	9.034	2.229
2	7.194	1.775
	(b) <i>TiO</i> ₂ .	

Table 3: Propagation constant and effective refractive index in a planar dielectric waveguide with $d = 5\mu m$ and $\lambda = 1.55\mu m$.

As we can see by the results above, the waveguide with core made by TiO_2 confines light much more than the one made by SiO_2 .

1.2 Rectangular dielectric waveguide

Now, to solve the problem of a rectangular dielectric waveguide, we will use the Marcatili's approximation, that is, we will consider that E(x,y) = X(x)Y(y). In other words, this problem is reduced to two planar dielectric waveguide problems (solved in Sec. 1.1).

Let's start with the analysis of the number of modes for the waveguide made of SiO_2 with $w = 6\mu m$ and $t = 2\mu m$, for a input light with $\lambda = 1.55\mu m$. The characteristic equation and the diagram with the guided modes are shown in Fig. 3a and 3b, respectively.

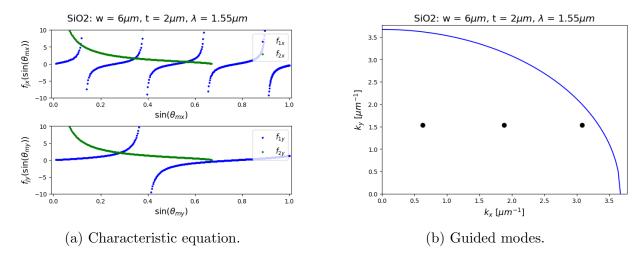


Figure 3: Solution for the guided modes in a rectangular dielectric waveguide with a SiO_2 core, $w = 6\mu m$, $t = 2\mu m$, and $\lambda = 1.55\mu m$.

The propagation constant and the refractive index for the guided modes are organized in Tab. 3a for SiO_2 and in Tab. 3b for TiO_2 .

Mode	$\beta[\mu m^{-1}]$	n_{eff}
(0,0)	5.211	1.285
(1,0)	4.901	1.209
(2,0)	4.247	1.048
	(a) SiO_2 .	

Mode	$\beta[\mu m^{-1}]$	n_{eff}
(0,0)	9.401	2.319
(1,0)	8.793	2.169
(2,0)	7.453	1.839
(3,0)	4.928	1.216
	(b) TiO_2 .	

Table 4: Propagation constant and effective refractive index in a rectangular dielectric waveguide with $w = 6\mu m$, $t = 3\mu m$, and $\lambda = 1.55\mu m$.

As you can see by the results above, further from confining more the light inside the core, the TiO_2 waveguide also present one more mode than the SiO_2 waveguide for the same width and thickness parameters.

2 COMSOL analysis

2.1 Individual guides

Now, let's model the rectangular dielectric waveguide in COMSOL Multiphysics and compare the results with those obtained using the Marcatili's method. Consider from now on the cladding material to be air $(n_2 = 1.000)$, the input wavelength to be $\lambda = 1.55 \mu m$, the core width to be $w = 6 \mu m$ and the core thickness to be $t = 2 \mu m$.

Given the dispersion relation you can calculate the relative permittivity by Eq. (6).

$$\epsilon_r(\lambda) = \frac{n(\lambda)^2}{\mu_r(\lambda)} \tag{6}$$

Also, consider the following parameters for the first simulation:

- Core material: SiO_2 .
- Dispersion relation: Eq. (1d).
- Relative permeability: 1.
- Electric condutivity: $\sigma = 1 \cdot 10^{12} S/m$.

I ran the simulation for the first six modes, obtained the effective refractive index and calculated the propagation constant by $\beta = n_{eff}/k_0$ where $k_0 = 2\pi/\lambda$. I also verified if the values for β satisfy the guiding condition $k_0 n_2 \leq \beta \leq k_0 n_1$.

From the surface ($\|\mathbf{E}\|$) and arrow plot (Ex and Ey) I could realize the similarities of some modes, with the main different of the transverse electric field being aligned in vertically or horizontally as indicated by Fig. 4b and ??, respectively.

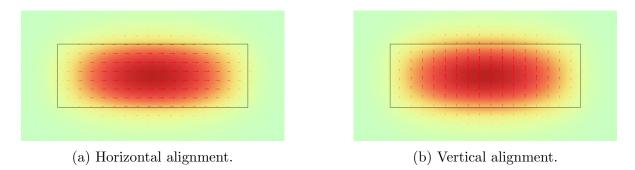


Figure 4: Surface and arrow plots for the first two modes of the SiO_2 waveguide.

Different spatial distribution was also observed for higer-order modes like in the third and fifth solutions displayed in Fig. 5a and 5b, respectively.

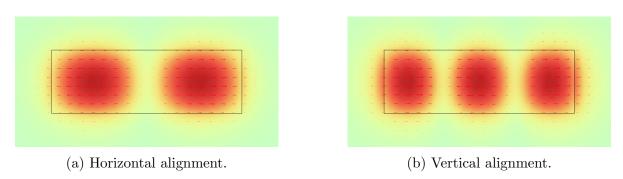


Figure 5: Surface and arrow plots for the E-field for the third and fifth solutions of the SiO_2 waveguide.

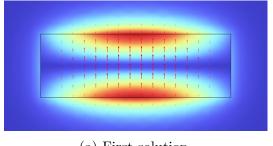
Using the relations in Eq. 7, I could generate the surface and arrow plot for the H-field.

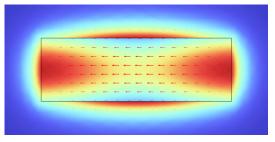
$$H_x = \frac{1}{i\omega\mu} \left(\frac{dE_z}{dy} - \frac{dE_y}{dz} \right) \tag{7a}$$

$$H_y = \frac{1}{i\omega\mu} \left(\frac{dE_x}{dz} - \frac{dE_z}{dx} \right) \tag{7b}$$

$$H_z = \frac{1}{i\omega\mu} \left(\frac{dE_y}{dx} - \frac{dE_x}{dy} \right) \tag{7c}$$

The first two solutions are shown in Fig. 6. As you can see, the H-field present a spatial distribution very different than the electric field.





(a) First solution.

(b) Second solution.

Figure 6: Surface and arrow plots for the H-field for the first two solutions of the SiO_2 waveguide.

These modes COMSOL found, are they TE or TM modes? Or even, are they hybrid modes (EH/HE)? To answer this, let's analyse the average of the electrical and H-field components for each modal solution considering just the core region.

Solution	\overline{E}_x	\overline{E}_y	\overline{E}_z	Solution	\overline{H}_x	\overline{H}_y	\overline{H}_z
1	35.6220	0.11970	3.1307	1	1.3620	1.1206	15.6140
2	0.19101	15.9590	2.7269	2	3.1532	0.66509	4.1252
3	17.6090	0.12490	3.1633	3	1.3802	2.2463	7.7342
4	0.39748	15.6620	2.6364	4	3.0498	1.3204	8.2683
5	11.5400	0.17708	3.2134	5	1.4181	3.3555	5.0526
6	0.68953	15.5830	2.5424	6	2.9503	1.9693	12.6490

⁽a) Electric field. The components are in V/m.

Table 5: Numerical values of propagation constant and effective refractive index for the first 6 modes obtained with COMSOL for the SiO_2 and TiO_2 waveguides.

As you can see by the tables above, the z-component of the electric and H-field are comparable to the x and y components, so the mode I found are hybrid modes of the type HE $(E_z > H_z)$.

Now consider the following parameters for the second simulation:

- Core material: TiO_2 .
- Dispersion relation: Eq. (1b).
- Relative permeability: 1.
- Electric condutivity: $\sigma = 1 \cdot 10^{12} S/m$.

Afterwards, I placed the results for β and n_{eff} obtained for the SiO_2 and TiO_2 waveguides in Tab. 6. As you can see, for the same solution number, the modes for the TiO_2 case present higher value of β , confining more the light within the core when compared to the SiO_2 waveguide.

⁽b) H-field. The components are in $[\cdot 10^{-3}H/m].$

Solution	$\beta[\mu m^{-1}]$	n_{eff}		Mode	$\beta[\mu m^{-1}]$
1	4.555	1.124		1	6.005
2	4.536	1.119		2	6.024
3	4.482	1.106		3	6.104
4	4.468	1.102		4	6.130
5	4.361	1.076		5	6.163
6	4.353	1.074		5	6.193
	(a) SiO_2 .		_		(b) TiO_2 .

Table 6: Numerical values of propagation constant and effective refractive index for the first 6 modes obtained with COMSOL for the SiO_2 and TiO_2 waveguides.

The modes found in this section don't agree with the TE modes we calculated in Sec. 1.2, where we used the variable separation approximation. Since the solver of COMSOL don't use this approximation, it simply solves the eigenvalue equation Eq. 8 using a numerical method, COMSOL is to be trusted.

$$\nabla \times \left(\frac{1}{\mu_r} \nabla \times \mathbf{E}\right) = k_0^2 \epsilon_r \mathbf{E} \tag{8}$$

2.2 Coupled guides

Now, let's consider a waveguide made by an air cladding and two equal cores. The geometrical parameters of the simulations are as follow:

- Cladding:
 - $w = 30 \mu m.$
 - $-t = 15 \mu m.$
- Core 1 and 2:
 - $w = 6\mu m.$
 - $-t=2\mu m.$

Varying the gap distance d between the cores for the SiO_2/SiO_2 waveguide, we get the plots of Fig. 7. You can see that at $d=1\mu m$, the modes of the different cores almost don't perceive the modes of the adjascent core. As you decrease the gap between them, the system tends to converge to one waveguide at $d=0\mu m$ with $w=w_{core1}+w_{core}=12\mu m$ and $t=2\mu m$.

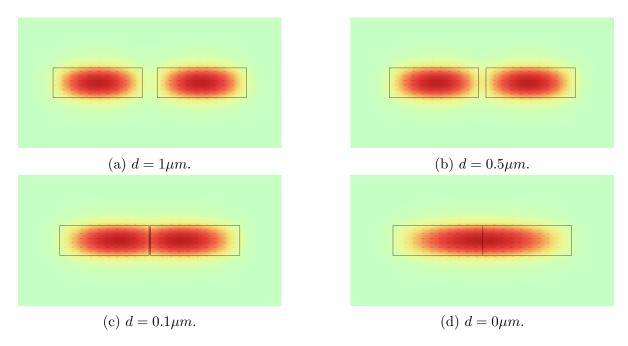


Figure 7: Surface and arrow plots for the E-field for the first solution of the SiO_2/SiO_2 coupled waveguide for different gaps d.

To explore the high confinement of the TiO_2 , we put the SiO_2/SiO_2 waveguide to the side of TiO_2/TiO_2 waveguide for $d=0.5\mu m$. As expected, the overlaping region for the TiO_2/TiO_2 guide is smaller for the fundamental mode. Something more interesting happens when we consider the core of different materials, the SiO_2/TiO_2 . Only the core of TiO_2 guides light.

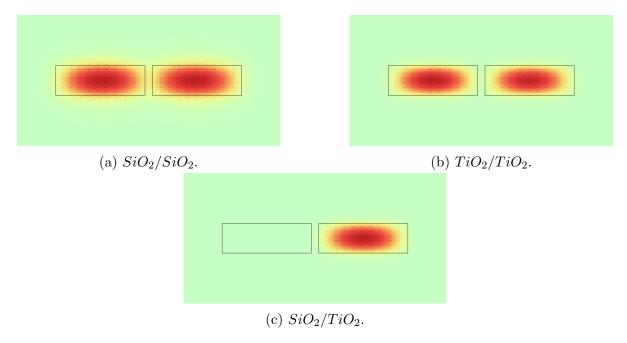


Figure 8: Comparison between the waveguides SiO_2/SiO_2 , TiO_2/TiO_2 , and SiO_2/TiO_2 for $d=0.5\mu m$.